MC74LCX139

Dual Low–Voltage CMOS 2-to-4 Decoder/Demultiplexer

With 5V–Tolerant Inputs

The MC74LCX139 is a high performance, 2–to–4 decoder/ demultiplexer operating from a 2.3 to 3.6 V supply. High impedance TTL compatible inputs significantly reduce current loading to input drivers while TTL compatible outputs offer improved switching noise performance. A V_I specification of 5.5 V allows MC74LCX139 inputs to be safely driven from 5 V devices. The MC74LCX139 is suitable for memory address decoding and other TTL level bus oriented applications.

The MC74LCX139 high–speed 2–to–4 decoder/demultiplexer accepts two binary weighted inputs (A0, A1) and, when enabled, provides four mutually exclusive active–LOW outputs. The LCX139 features an active low Enable input. All outputs will be HIGH unless En is LOW. The LCX139 can be used as an 8–output demultiplexer by using one of the active–LOW Enable inputs as the data input and the other Enable input as a strobe. The Enable inputs which are not used must be permanently tied to ground.

Current drive capability is 24 mA at the outputs.

- Designed for 2.3 to 3.6 V V_{CC} Operation
- 5 V Tolerant Inputs – Interface Capability With 5 V TTL Logic
- LVTTL Compatible
- LVCMOS Compatible
- 24 mA Balanced Output Sink and Source Capability
- Near Zero Static Supply Current (10 μA) Substantially Reduces System Power Requirements
- Latchup Performance Exceeds 500 mA
- ESD Performance: Human Body Model >2000 V; Machine Model >200 V

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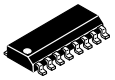
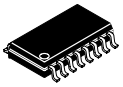


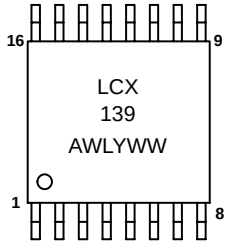
SO–16
D SUFFIX
CASE 751B

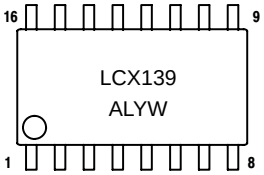
TSSOP–16
DT SUFFIX
CASE 948F



EIAJ SO–16
M SUFFIX
CASE 966

MARKING DIAGRAMS





A = Assembly Location
WL, L = Wafer Lot
YY, Y = Year
WW, W = Work Week

ORDERING INFORMATION

Device	Package	Shipping
MC74LCX139D	SO–16	48 Units/Rail
MC74LCX139DR2	SO–16	2500 Units/Reel
MC74LCX139DT	TSSOP–16	96 Units/Rail
MC74LCX139DTEL	TSSOP–16	2000 Units/Reel
MC74LCX139DTR2	TSSOP–16	2000 Units/Reel
MC74LCX139M	EIAJ SO–16	48 Units/Rail
MC74LCX139MEL	EIAJ SO–16	2000 Units/Reel

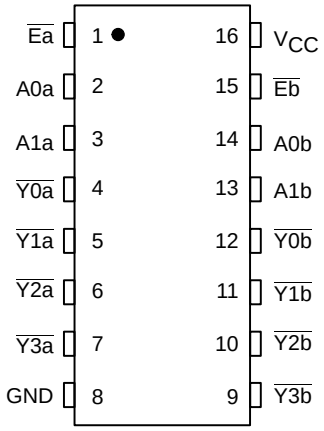


Figure 1. Pin Assignment

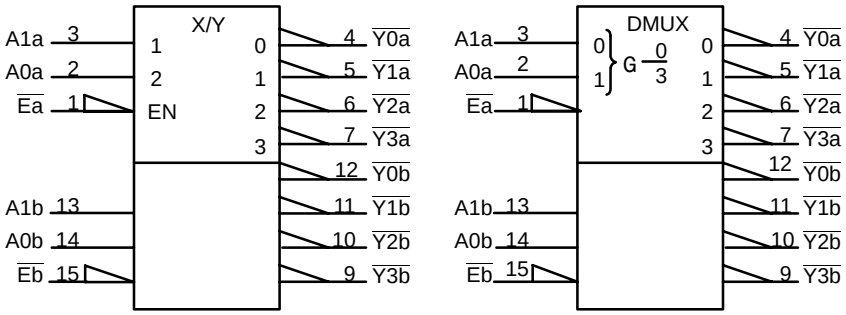


Figure 2. IEC Logic Diagram

PIN NAMES

Pins	Function
A0n–A1n	Address Inputs
En	Enable Inputs
$\overline{Y0n}$–$\overline{Y3n}$	Outputs

TRUTH TABLE

Inputs			Outputs			
$\overline{E}$	A1	A0	$\overline{Y0}$	$\overline{Y1}$	$\overline{Y2}$	$\overline{Y3}$
H	X	X	H	H	H	H
L	L	L	L	H	H	H
L	L	H	H	L	H	H
L	H	L	H	H	L	H
L	H	H	H	H	H	L

H = High Voltage Level;
L = Low Voltage Level;
Z = High Impedance State

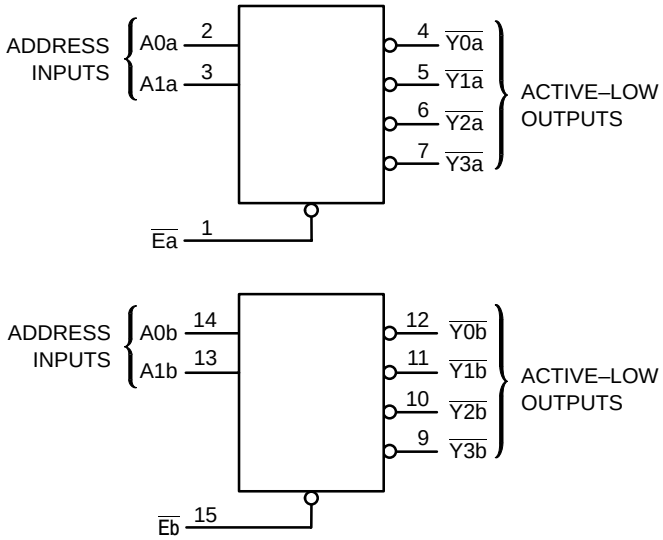


Figure 3. Logic Diagram

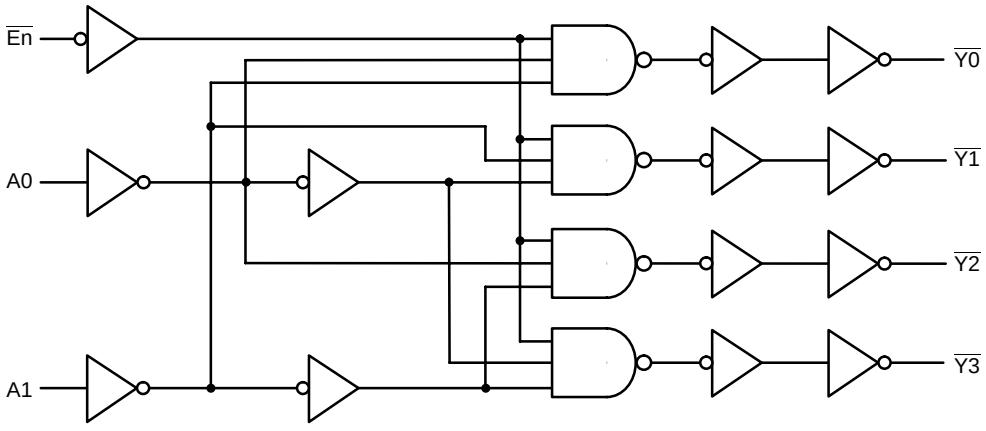


Figure 4. Expanded Logic Diagram
(1/2 of Device)

MAXIMUM RATINGS

Symbol	Parameter	Value	Condition	Unit
V_{CC}	DC Supply Voltage	–0.5 to +7.0		V
V_I	DC Input Voltage	$–0.5 \le V_I \le +7.0$		V
V_O	DC Output Voltage	$–0.5 \le V_O \le V_{CC} + 0.5$	Output in HIGH or LOW State. (Note 1.)	V
I_{IK}	DC Input Diode Current	–50	$V_I < GND$	mA
I_{OK}	DC Output Diode Current	–50	$V_O < GND$	mA
		+50	$V_O > V_{CC}$	mA
I_O	DC Output Source/Sink Current	±50		mA
I_{CC}	DC Supply Current Per Supply Pin	±100		mA
I_{GND}	DC Ground Current Per Ground Pin	±100		mA
T_{STG}	Storage Temperature Range	–65 to +150		°C

Maximum Ratings are those values beyond which damage to the device may occur. Exposure to these conditions or conditions beyond those indicated may adversely affect device reliability. Functional operation under absolute maximum–rated conditions is not implied. Functional operation should be restricted to the Recommended Operating Conditions.

1. I_O absolute maximum rating must be observed.

RECOMMENDED OPERATING CONDITIONS

Symbol	Parameter		Min	Typ	Max	Unit
V_{CC}	Supply Voltage	Operating Data Retention Only	2.0 1.5	2.3 to 3.3	3.6 3.6	V
V_I	Input Voltage		0		5.5	V
V_O	Output Voltage	(HIGH or LOW State)	0		V_{CC}	V
I_{OH}	HIGH Level Output Current	V_{CC} = 3.0 V – 3.6 V V_{CC} = 2.7 V – 3.0 V V_{CC} = 2.3 V – 2.7 V			–24 –12 –8	mA
I_{OL}	LOW Level Output Current	V_{CC} = 3.0 V – 3.6 V V_{CC} = 2.7 V – 3.0 V V_{CC} = 2.3 V – 2.7 V			+24 +12 +8	mA
T_A	Operating Free–Air Temperature		–40		+85	°C
$\Delta t/\Delta V$	Input Transition Rise or Fall Rate, V_{IN} from 0.8 V to 2.0 V, V_{CC} = 3.0 V		0		10	ns/V

DC ELECTRICAL CHARACTERISTICS

Symbol	Characteristic	Condition	T_A = –40°C to +85°C		Unit
			Min	Max	
V_{IH}	HIGH Level Input Voltage (Note 2.)	2.3 V ≤ V_{CC} ≤ 2.7 V	1.7		V
		2.7 V ≤ V_{CC} ≤ 3.6 V	2.0		
V_{IL}	LOW Level Input Voltage (Note 2.)	2.3 V ≤ V_{CC} ≤ 2.7 V		0.7	V
		2.7 V ≤ V_{CC} ≤ 3.6 V		0.8	
V_{OH}	HIGH Level Output Voltage	2.3 V ≤ V_{CC} ≤ 3.6 V; I_{OL} = 100 μA	V_{CC} – 0.2		V
		V_{CC} = 2.3 V; I_{OH} = –8 mA	1.7		
		V_{CC} = 2.7 V; I_{OH} = –12 mA	2.2		
		V_{CC} = 3.0 V; I_{OH} = –18 mA	2.4		
		V_{CC} = 3.0 V; I_{OH} = –24 mA	2.2		
V_{OL}	LOW Level Output Voltage	2.3 V ≤ V_{CC} ≤ 3.6 V; I_{OL} = 100 μA		0.2	V
		V_{CC} = 2.3 V; I_{OL}= 8 mA		0.7	
		V_{CC} = 2.7 V; I_{OL}= 12 mA		0.4	
		V_{CC} = 3.0 V; I_{OL} = 16 mA		0.4	
		V_{CC} = 3.0 V; I_{OL} = 24 mA		0.55	
I_I	Input Leakage Current	2.3 V ≤ V_{CC} ≤ 3.6 V; 0 V ≤ V_I ≤ 5.5 V		±5	μA
I_{CC}	Quiescent Supply Current	2.3 ≤ V_{CC} ≤ 3.6 V; V_I = GND or V_{CC}		10	μA
		2.3 ≤ V_{CC} ≤ 3.6 V; 3.6 ≤ V_I or V_O ≤ 5.5 V		±10	
ΔI_{CC}	Increase in I_{CC} per Input	2.3 ≤ V_{CC} ≤ 3.6 V; V_{IH} = V_{CC} – 0.6 V		500	μA

2. These values of V_I are used to test DC electrical characteristics only.

AC CHARACTERISTICS $t_R = t_F$ = 2.5 ns; C_L = 50 pF; R_L = 500 Ω

Symbol	Parameter	Limits						Unit
		T_A= –40°C to +85°C						
		V_{CC}= 3.0 V to 3.6 V		V_{CC}= 2.7 V		V_{CC}= 2.3 V to 2.7 V		
		C_L= 50 pF		C_L= 50 pF		C_L= 30pF		
		Min	Max	Min	Max	Min	Max	
t_{PLH}	Propagation Delay	0.8	6.2	1.0	7.3	0.8	9.3	ns
t_{PHL}	A to Y	0.8	6.2	1.0	7.3	0.8	9.3	ns
t_{PLH}	Propagation Delay	0.8	4.7	1.0	5.2	0.8	7.2	ns
t_{PHL}	E to Y	0.8	4.7	1.0	5.2	0.8	7.2	ns
t_{OSHL}	Output–to–Output Skew (Note 3.)		1.0					ns
t_{OSLH}			1.0					ns

3. Skew is defined as the absolute value of the difference between the actual propagation delay for any two separate outputs of the same device. The specification applies to any outputs switching in the same direction, either HIGH–to–LOW (t_{OSHL}) or LOW–to–HIGH (t_{OSLH}); parameter guaranteed by design.

CAPACITIVE CHARACTERISTICS

Symbol	Parameter	Condition	Typical	Unit
C_{IN}	Input Capacitance	V_{CC} = 3.3 V, V_I = 0 V or V_{CC}	7	pF
C_{OUT}	Output Capacitance	V_{CC} = 3.3 V, V_I = 0 V or V_{CC}	8	pF
C_{PD}	Power Dissipation Capacitance	10MHz, V_{CC} = 3.3 V, V_I = 0 V or V_{CC}	25	pF

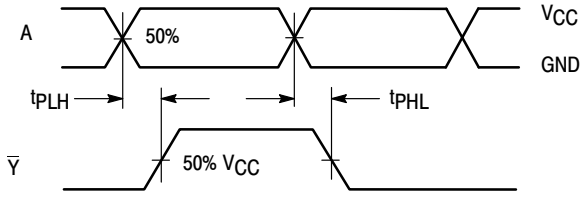


Figure 5. Waveform 1 Prop Delays

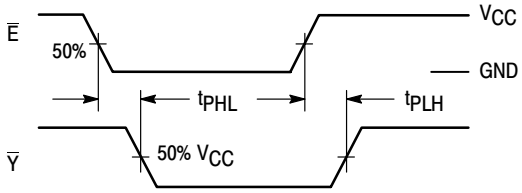
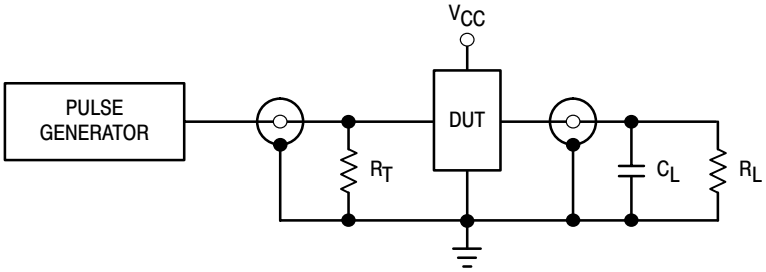


Figure 6. Waveform 2 Output Enable



C_L = 50 pF or equivalent (Includes jig and probe capacitance)
$R_L = R_1$ = 500 Ω or equivalent
$R_T = Z_{OUT}$ of pulse generator (typically 50 Ω)

Figure 7. Test Circuit